

**Features**

- Center amplifying gate
- Metal case with ceramic insulator
- Low on-state and switching losses

**I<sub>T(AV)</sub>**      **4900 A**  
**V<sub>DRM/V<sub>RRM</sub></sub>**      **400-1000V**  
**I<sub>TSM</sub>**      **66 kA**  
**I<sup>2</sup>t**      **21780 10<sup>3</sup>A<sup>2</sup>S**

**Typical Applications**

- AC controllers
- DC and AC motor control
- Controlled rectifiers



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>j</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>T(AV)</sub>	Mean on-state current	180° half sine wave 50Hz Double side cooled, T <sub>c</sub> =70°C				4900	
V <sub>DRM</sub> V <sub>RRM</sub>	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms	125	400		1000	V
I <sub>DRM</sub> I <sub>RRM</sub>	Repetitive peak current	at V <sub>DRM</sub> at V <sub>RRM</sub>	125			250	mA
I <sub>TSM</sub>	Surge on-state current	10ms half sine wave	125			66	kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination	V <sub>R</sub> =0.6V <sub>RRM</sub>				21780	A <sup>2</sup> s*10 <sup>3</sup>
V <sub>TO</sub>	Threshold voltage		125			0.88	V
r <sub>T</sub>	On-state slope resistance		125			0.06	mΩ
V <sub>TM</sub>	Peak on-state voltage	I <sub>TM</sub> =5000A, F=70kN	25			1.18	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> =0.67V <sub>DRM</sub>	125			1000	V/μs
di/dt	Critical rate of rise of on-state voltage current	V <sub>DM</sub> = 67%V <sub>DRM</sub> to 4000A, Gate pulse t <sub>r</sub> ≤0.5μs I <sub>GM</sub> =1.5A	125			250	A/μs
Q <sub>rr</sub>	Recovery charge	I <sub>TM</sub> =2000A, tp=2000μs, di/dt=-20A/μs, V <sub>R</sub> =50V	125		3000		μC
I <sub>GT</sub>	Gate trigger current			40		300	mA
V <sub>GT</sub>	Gate trigger voltage	V <sub>A</sub> =12V, I <sub>A</sub> =1A	25	0.8		3.0	V
I <sub>H</sub>	Holding current			20		300	mA
V <sub>GD</sub>	Non-trigger gate voltage	V <sub>DM</sub> =67%V <sub>DRM</sub>	125	0.3			V
R <sub>th(j-c)</sub>	Thermal resistance Junction to case	At 180° sine double side cooled				0.007	°C /W
R <sub>th(c-h)</sub>	Thermal resistance case to heatsink	Clamping force 70.0kN				0.002	
F <sub>m</sub>	Mounting force			63		84	kN
T <sub>stg</sub>	Stored temperature			-40		140	°C
W <sub>t</sub>	Weight				1390		g
Outline		P20					

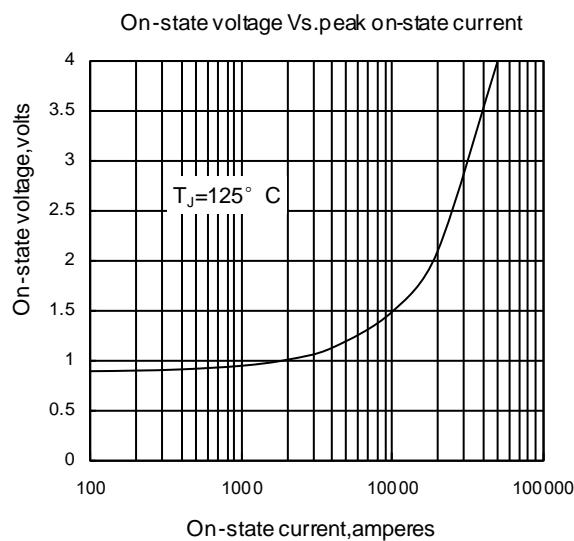


Fig1

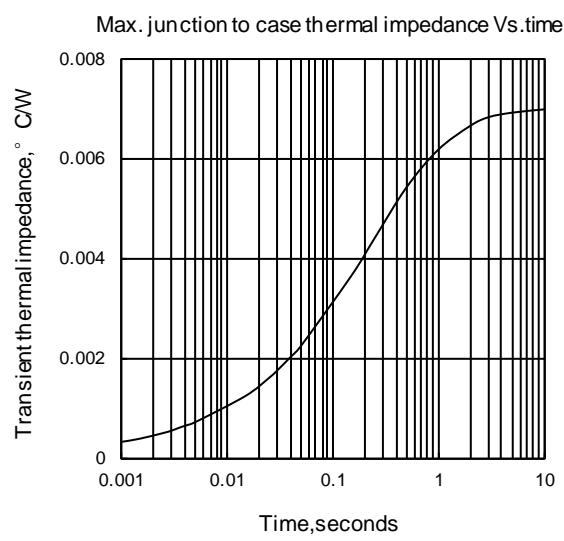


Fig2

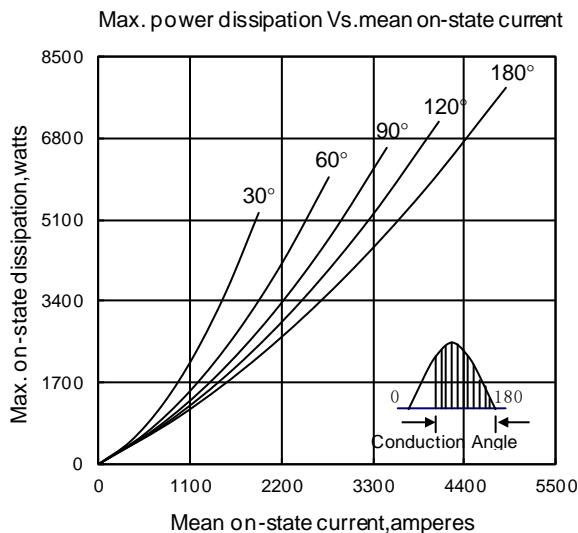


Fig3

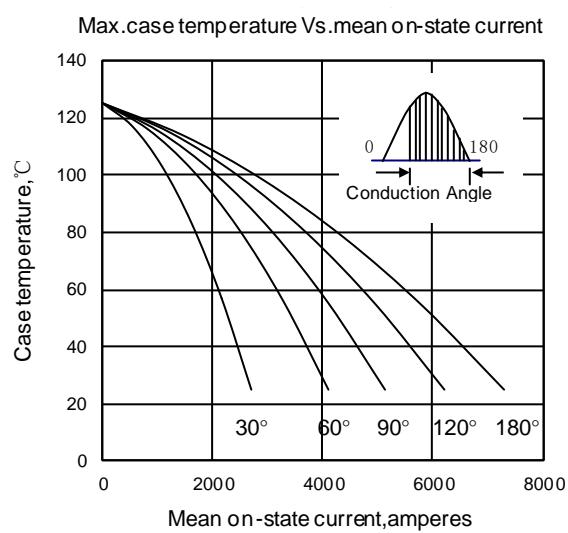


Fig4

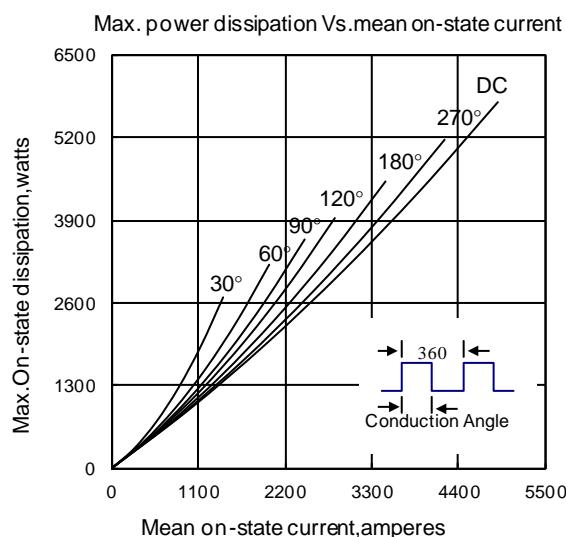


Fig5

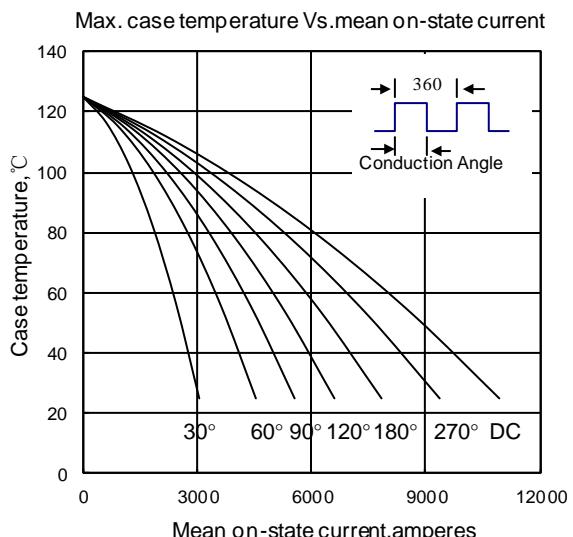


Fig6

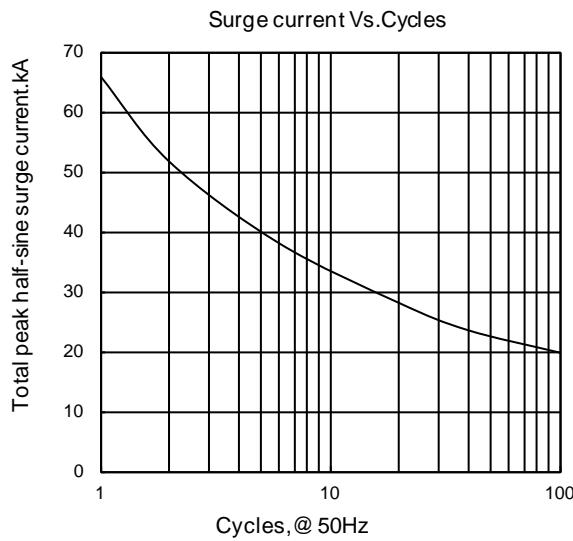


Fig7

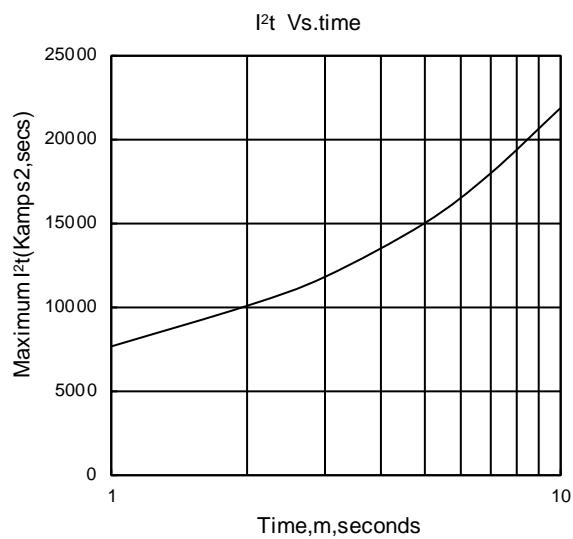


Fig8

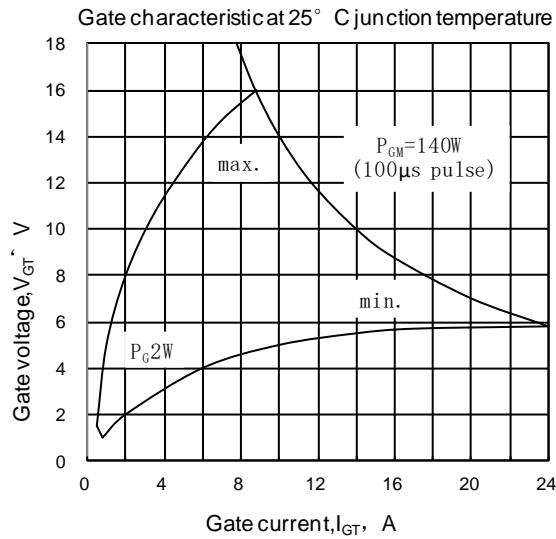


Fig9

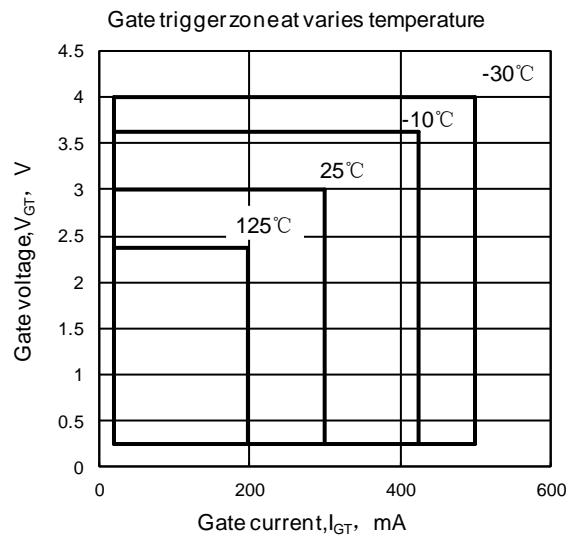


Fig10

